## NSN 5961-01-331-4105

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-331-4105 **Inclosure Material:** Plastic **Overall Length:** Between 14.23 millimeters and 15.87 millimeters **Terminal Length:** Between 2.04 millimeters and 2.92 millimeters **Overall Height:** Between 3.56 millimeters and 4.82 millimeters **Overall Width:** Between 9.66 millimeters and 10.66 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 60.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**